SN74AVCB324245 32-BIT DUAL-SUPPLY BUS TRANSCEIVER

WITH CONFIGURABLE VOLTAGE TRANSLATION AND 3-STATE OUTPUTS

SCES485A-AUGUST 2003-REVISED MARCH 2005

#### FEATURES

- Member of the Texas Instruments Widebus+™ Family
- DOC<sup>™</sup> Circuitry Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation
- **Dynamic Drive Capability Is Equivalent to** Standard Outputs With  $I_{OH}$  and  $I_{OL}$  of
  - $-\pm 24$  mA at 3-V V<sub>CC</sub>
  - $-\pm$ 15 mA at 2.3-V V<sub>CC</sub>

**RUMENTS** 

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- $-\pm$ 9 mA at 1.65-V V<sub>CC</sub>
- $\pm$ 6 mA at 1.4-V V<sub>CC</sub>
- Control Inputs V<sub>IH</sub>/V<sub>II</sub> Levels Are Referenced to V<sub>CCB</sub> Voltage
- If Either V<sub>CC</sub> Input Is at GND, Both Ports Are in the High-Impedance State

## DESCRIPTION/ORDERING INFORMATION

- Inputs/Outputs Can Tolerate up to 4.6 V, Which Allows Mixed-Voltage-Mode Data Communications
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.4-V to 3.6-V Power-Supply Range
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

This 32-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V<sub>CCA</sub>. V<sub>CCA</sub> accepts any supply voltage from 1.4 V to 3.6 V. The B port is designed to track V<sub>CCB</sub>. V<sub>CCB</sub> accepts any supply voltage from 1.4 V to 3.6 V. This allows for universal low-voltage bidirectional translation between any of the 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes.

The SN74AVCB324245 is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the outputs so the buses are effectively isolated.

The SN74AVCB324245 is designed so that the control pins (1DIR, 2DIR, 1 $\overline{OE}$ , and 2 $\overline{OE}$ ) are supplied by V<sub>CCB</sub>.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  shall be tied to V<sub>CCB</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. If either V<sub>CC</sub> input is at GND, both ports are in the high-impedance state.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
4000 to 0500	LFBGA – GKE		SN74AVCB324245KR	WD 40 45
–40°C to 85°C	LFBGA – ZKE (Pb-free)	Tape and reel	74AVCB324245ZKER	WD4245

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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SCES485A-AUGUST 2003-REVISED MARCH 2005



**GKE OR ZKE PACKAGE** (TOP VIEW) 1 2 3 4 5 6 000000 Α 000000 в 000000 С 000000 D 000000 Е 000000 F 000000 G 000000 Н 000000 J 000000 κ L 000000 000000 Μ 000000 Ν 000000 Ρ 000000 R 000000 т

#### **TERMINAL ASSIGNMENTS**

	1	2	3	4	5	6
Α	1B2	1B1	1DIR	1 <del>0E</del>	1A1	1A2
В	1B4	1B3	GND	GND	1A3	1A4
С	1B6	1B5	V <sub>CCB</sub>	V <sub>CCA</sub>	1A5	1A6
D	1B8	1B7	GND	GND	1A7	1A8
Е	2B2	2B1	GND	GND	2A1	2A2
F	2B4	2B3	V <sub>CCB</sub>	V <sub>CCA</sub>	2A3	2A4
G	2B6	2B5	GND	GND	2A5	2A6
н	2B7	2B8	2DIR	2 <del>0E</del>	2A8	2A7
J	3B2	3B1	3DIR	3 <del>0E</del>	3A1	3A2
К	3B4	3B3	GND	GND	3A3	3A4
L	3B6	3B5	V <sub>CCB</sub>	V <sub>CCA</sub>	3A5	3A6
М	3B8	3B7	GND	GND	3A7	3A8
Ν	4B2	4B1	GND	GND	4A1	4A2
Р	4B4	4B3	V <sub>CCB</sub>	V <sub>CCA</sub>	4A3	4A4
R	4B6	4B5	GND	GND	4A5	4A6
т	4B7	4B8	4DIR	4 <del>0E</del>	4A8	4A7

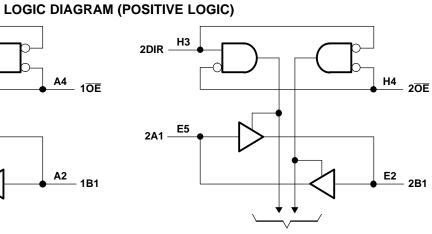
#### FUNCTION TABLE (EACH 8-BIT SECTION)

rs	OPERATION
DIR	OFERATION
L	B data to A bus
Н	A data to B bus
Х	Isolation
	DIR

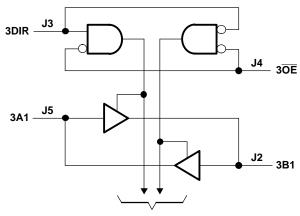
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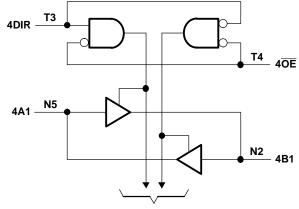
**To Seven Other Channels** 







**To Seven Other Channels** 



**To Seven Other Channels** 

SCES485A-AUGUST 2003-REVISED MARCH 2005

#### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CCA</sub> , V <sub>CCB</sub>	Supply voltage range		-0.5	4.6	V
		I/O ports (A port)	-0.5	4.6	
VI	Input voltage range <sup>(2)</sup>	I/O ports (B port)	-0.5	4.6	V
		Control inputs	-0.5	4.6	
V	Voltage range applied to any output	A port	-0.5	4.6	V
Vo	in the high-impedance or power-off state <sup>(2)</sup>	B port	-0.5	4.6	v
V	Valtage respectively to an instant in the high or law state $(2)(3)$	A port	-0.5	V <sub>CCA</sub> + 0.5	V
Vo	Voltage range applied to any output in the high or low state $^{(2)}$ $^{(3)}$	B port	-0.5	V <sub>CCB</sub> + 0.5	v
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>0</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through each $V_{CCA}$ , $V_{CCB}$ , or GND			±100	mA
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	GKE/ZKE package		40	°C/W
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating" conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(2)

 (3) The output positive-voltage rating may be exceeded up to 4.6 V maximum it tn
(4) The package thermal impedance is calculated in accordance with JESD 51-7. The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.



SCES485A-AUGUST 2003-REVISED MARCH 2005

# Recommended Operating Conditions<sup>(1)(2)(3)</sup>

			V <sub>CCI</sub>	V <sub>cco</sub>	MIN	MAX	UNIT
V <sub>CCA</sub>	Supply voltage				1.4	3.6	V
V <sub>CCB</sub>	Supply voltage				1.4	3.6	V
			1.4 V to 1.95 V		$V_{CCI}  imes 0.65$	3.6	
V <sub>IH</sub>	High-level input voltage	Data inputs	1.95 V to 2.7 V		1.7	3.6	V
			2.7 V to 3.6 V		2	3.6	
			1.4 V to 1.95 V		0	$V_{CCI}  imes 0.35$	
V <sub>IL</sub>	Low-level input voltage	Data inputs	1.95 V to 2.7 V		0	0.7	V
			2.7 V to 3.6 V		0	0.8	
			1.4 V to 1.95 V		$V_{CCB}  imes 0.65$	V <sub>CCB</sub>	
V <sub>IH</sub>	High-level input voltage	Control inputs (referenced to V <sub>CCB</sub> )	1.95 V to 2.7 V		1.7		V
		(referenced to VCCB)	2.7 V to 3.6 V		2	V <sub>CCB</sub>	
			1.4 V to 1.95 V		0	$V_{\text{CCB}} \times 0.35$	
V <sub>IL</sub>	Low-level input voltage	Control inputs (referenced to V <sub>CCB</sub> )	1.95 V to 2.7 V		0	0.7	V
		(referenced to vCCB)	2.7 V to 3.6 V		0	0.8	
Vo	Output voltage				0	V <sub>cco</sub>	V
				1.4 V to 1.6 V		-2	
	Lich loval output ourroot			1.65 V to 1.95 V		-4	mA
I <sub>OH</sub>	High-level output current			2.3 V to 2.7 V		-8	mA
				3 V to 3.6 V		-12	
				1.4 V to 1.6 V		2	
	Level and and a second assume at			1.65 V to 1.95 V		4	
I <sub>OL</sub>	Low-level output current			2.3 V to 2.7 V		8	mA
				3 V to 3.6 V		12	
$\Delta t/\Delta v$	Input transition rise or fall	rate				5	ns/V
T <sub>A</sub>	Operating free-air temper	ature			-40	85	°C

(1)

V<sub>CCI</sub> is the V<sub>CC</sub> associated with the data input port. V<sub>CCO</sub> is the V<sub>CC</sub> associated with the output port. All unused data inputs of the device must be held at V<sub>CCI</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004. (2) (3)



SCES485A-AUGUST 2003-REVISED MARCH 2005

# Electrical Characteristics<sup>(1)(2)</sup>

over recommended operating free-air temperature range (unless otherwise noted)

PA	ARAMETER	TEST COND	ITIONS	V <sub>CCA</sub>	V <sub>CCB</sub>	MIN	-0.2 1.05 1.2 1.75 2.3 0.3 0.4 0.5 0.7 1.05 1.2 1.75 2.3 0.3 0.4 0.5 0.7 1.05 1.2 1.75 2.3 0.3 0.3 0.4 0.5 0.7 1.05 1.2 1.2 1.75 2.3 0.3 0.4 0.5 0.7 1.2 1.2 1.2 1.2 1.2 1.2 1.2 1.2	MAX	UNI
		I <sub>OH</sub> = -100 μA	$V_I = V_{IH}$	1.4 V to 3.6 V	1.4 V to 3.6 V	V <sub>CCO</sub> – 0.2			
		I <sub>OH</sub> = -2 mA	$V_I = V_{IH}$	1.4 V	1.4 V			0.2 0.35 0.45 0.55 0.7 0.7 0.35 0.45 0.7 ±2.5 ±10 ±10 ±10 ±12.5 ±12.5 ±12.5 ±12.5 ±12.5 ±12.5 ±12.5 ±12.5 ±12.5	
PARMETER     VOH	$I_{OH} = -4 \text{ mA}$	$V_I = V_{IH}$	1.65 V	1.65 V	1.2			V	
	I <sub>OH</sub> =8 mA	$V_I = V_{IH}$	2.3 V	2.3 V	1.75				
		I <sub>OH</sub> = -12 mA	$V_I = V_{IH}$	3 V	3 V	2.3			
		I <sub>OH</sub> = 100 μA	$V_{I} = V_{IL}$	1.4 V to 3.6 V	1.4 V to 3.6 V			0.2	
		$I_{OH} = 2 \text{ mA}$	$V_I = V_{IL}$	1.4 V	1.4 V			0.35	
V <sub>OL</sub>		$I_{OH} = 4 \text{ mA}$	$V_I = V_{IL}$	1.65 V	1.65 V			0.45	v
		I <sub>OH</sub> = 8 mA	$V_I = V_{IL}$	2.3 V	2.3 V			0.55	
		I <sub>OH</sub> = 12 mA	$V_I = V_{IL}$	3 V	3 V			0.7	
		$I_{OHD} = -6 \text{ mA}$	$V_{I} = V_{IH}$	1.4 V	1.4 V	1.05			
		$I_{OHD} = -9 \text{ mA}$	$V_{I} = V_{IH}$	1.65 V	1.65 V	1.2			
V <sub>OH</sub>		$I_{OHD} = -15 \text{ mA}$	$V_{I} = V_{IH}$	2.3 V	2.3 V	1.75			V
		$I_{OHD} = -24 \text{ mA}$	$V_{I} = V_{IH}$	3 V	3 V	2.3			
		I <sub>OHD</sub> = 6 mA	$V_{I} = V_{IL}$	1.4 V	1.4 V			0.35	
		I <sub>OHD</sub> = 9 mA	$V_{I} = V_{IL}$	1.65 V	1.65 V			0.45	
V <sub>OL</sub>		I <sub>OHD</sub> = 15 mA	$V_{I} = V_{IL}$	2.3 V	2.3 V			0.55	
		$I_{OHD} = 24 \text{ mA}$	$V_{I} = V_{IL}$	3 V	3 V			0.7	V Ац Ац Ац
I <sub>I</sub>	Control inputs	$V_I = V_{CCB}$ or GND		1.4 V to 3.6 V	3.6 V			±2.5	μA
				0 V	0 to 3.6 V			±10	
off		$V_{\rm I}$ or $V_{\rm O}$ = 0 to 3.6 V		0 to 3.6 V	0 V			±10	μ
	A or B ports		$\overline{OE} = V_{IH}$	3.6 V	3.6 V			±12.5	
oz <sup>(4)</sup>	B port	$V_0 = V_{CCO}$ or GND,	$\overline{OE} = don't$	0 V	3.6 V			±12.5	μA
	A port	$V_{I} = V_{CCI}$ or GND	care	3.6 V	0 V			±12.5	
				1.6 V	1.6 V			40	
				1.95 V	1.95 V			40	
				2.7 V	2.7 V			60	
CCA		$V_I = V_{CCI}$ or GND,	$I_{O} = 0$	0 V	3.6 V			-80	μ
				3.6 V	0 V			80	
				3.6 V	3.6 V			80	
				1.6 V	1.6 V			40	
				1.95 V	1.95 V			40	
				2.7 V	2.7 V			60	
ССВ		$V_I = V_{CCI}$ or GND,	I <sub>O</sub> = 0	0 V	3.6 V			80	μA
				3.6 V	0 V			-80	
				3.6 V	3.6 V			80	
C <sub>i</sub>	Control inputs	$V_{I} = 3.3 \text{ V or GND}$		3.3 V	3.3 V		4		pF
C <sub>io</sub>	A or B ports	$V_0 = 3.3 \text{ V or GND}$		3.3 V	3.3 V		5		pF

 $\begin{array}{ll} (1) & V_{CCI} \text{ is the } V_{CC} \text{ associated with the input port.} \\ (2) & V_{CCO} \text{ is the } V_{CC} \text{ associated with the output port.} \\ (3) & \text{All typical values are at } T_A = 25^\circ\text{C}. \\ (4) & \text{For I/O ports, the parameter } I_{OZ} \text{ includes the input leakage current.} \\ \end{array}$ 

SCES485A-AUGUST 2003-REVISED MARCH 2005

## **Switching Characteristics**

over recommended operating free-air temperature range, V\_{CCA} = 1.5 V  $\pm$  0.1 V (see Figure 2)

PARAMETER	FROM (INPUT)	TO	V <sub>CCB</sub> = ± 0.7	V <sub>CCB</sub> = 1.5 V ± 0.1 V		1.8 V 5 V	V <sub>CCB</sub> = ± 0.2		V <sub>ССВ</sub> = ± 0.3		UNIT	
		(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
	А	В	1.7	6.7	1.9	6.4	1.8	5.5	1.5	5.8		
t <sub>pd</sub>	В	A	1.8	6.8	1.7	6.2	1.6	5.9	1.5	5.9	ns	
	ŌĒ	A	2.1	9	2.9	9.8	3.2	10	3	9.8	5	
Len	UE	В	2.5	8.4	2.4	8	2.3	7.6	2.2	7.5	ns	
t <sub>dis</sub>	ŌĒ	A	2.1	7.1	2.3	6.4	1.7	5.1	1.6	4.8		
	ÛE	В	2.2	6.9	1.8	6.4	1.1	5.8	1.8	5.7	ns	

### **Switching Characteristics**

over recommended operating free-air temperature range, V<sub>CCA</sub> = 1.8 V  $\pm$  0.15 V (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)		V <sub>CCB</sub> = 1.5 V ± 0.1 V		1.8 V 5 V	V <sub>ССВ</sub> = ± 0.2		V <sub>CCB</sub> = 3.3 V ± 0.3 V		UNIT		
	(INPOT)	(001201)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX			
	А	В	1.7	6.4	1.8	6	1.7	4.7	1.6	4.3	5		
t <sub>pd</sub> B	А	2	6.6	1.8	6	1.8	5.6	1.8	5.5	ns			
+	ŌĒ	А	1.8	7.6	2.6	7.7	2.6	7.6	2.6	7.4	20		
t <sub>en</sub>	UE	В	2.5	8.2	2.5	7.5	2.4	7.4	2.3	7.2	ns		
+			, OE	А	1.8	7	2.5	6.3	1.8	4.7	1.7	4.4	
t <sub>dis</sub>	UE	В	2.5	6.7	2.3	6.1	2.2	5.5	1.3	5.3	ns		

## **Switching Characteristics**

over recommended operating free-air temperature range, V\_{CCA} = 2.5 V  $\pm$  0.2 V (see Figure 2)

PARAMETER	FROM	TO		$V_{CCB}$ = 1.5 V $\pm$ 0.1 V		V <sub>CCB</sub> = 1.8 V ± 0.15 V		2.5 V 2 V	V <sub>CCB</sub> = 3.3 V ± 0.3 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	А	В	1.6	6	1.8	5.6	1.5	4	1.5	3.4	5
t <sub>pd</sub>	В	А	1.7	5.4	1.7	4.6	1.5	4	1.5	3.7	ns
	ŌĒ	А	1.7	5.7	2.2	5.5	2.2	5.3	2.2	5.1	20
t <sub>en</sub>	UE	В	3.1	6.1	2.5	5.6	2.2	5.3	1.9	4.2	ns
	<u>AF</u>	А	1.2	5.8	1.9	5	1.4	3.6	1.3	3.3	20
t <sub>dis</sub>	ŌĒ	В	2.4	6	3	5.2	1.4	3.6	1.2	3	ns

#### **Switching Characteristics**

over recommended operating free-air temperature range, V\_{CCA} = 3.3 V  $\pm$  0.3 V (see Figure 2)

PARAMETER	FROM	TO	V <sub>CCB</sub> = ± 0.1	1.5 V 1 V	V <sub>ССВ</sub> = ± 0.1		V <sub>ССВ</sub> = ± 0.2		V <sub>ССВ</sub> = ± 0.3		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	А	В	1.5	5.9	1.7	5.4	1.5	3.7	1.4	3.1	~~~
t <sub>pd</sub>	В	А	1.5	5.8	1.5	4.2	1.5	3.3	1.4	3.1	ns
	ŌĒ	А	1.6	4.9	2	4.5	2	4.3	1.9	4.1	~~~
t <sub>en</sub>	ÛE	В	2	5.1	2	4.6	2.2	5.2	1.9	4.1	ns
	ŌĒ	А	1.3	6.9	2.1	5.5	1.6	3.8	1.5	3.5	~~~
t <sub>dis</sub>	ÛE	В	2.3	5.5	1.9	4.5	1.3	3.5	1.2	3.5	ns



SCES485A-AUGUST 2003-REVISED MARCH 2005

#### **Operating Characteristics**

 $V_{CCA}$  and  $V_{CCB}$  = 3.3 V,  $T_A$  = 25°C

	PARAMETER		TEST C	ONDITIONS	TYP	UNIT
	Power-dissipation capacitance per transceiver,	Outputs enabled			14	
C <sub>pdA</sub>	A-port input, B-port output	Outputs disabled	0 0	6 40 MUL	7	- 5
C <sub>pdA</sub> (V <sub>CCA</sub> )	Power-dissipation capacitance per transceiver,	Outputs enabled	$C_{L} = 0,$	f = 10 MHz	20	pF
	B-port input, A-port output	Outputs disabled			7	
	Power-dissipation capacitance per transceiver,	Outputs enabled			20	
C <sub>pdB</sub>	A-port input, B-port output	Outputs disabled	0 0	6 40 MUL	7	
C <sub>pdB</sub> (V <sub>CCB</sub> )	Power-dissipation capacitance per transceiver,	Outputs enabled	$C_{L} = 0,$	f = 10 MHz	14	pF
	B-port input, A-port output	Outputs disabled			7	



#### **Output Description**

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The dynamic output control ( $DOC^{TM}$ ) circuitry is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical V<sub>OL</sub> vs I<sub>OL</sub> and V<sub>OH</sub> vs I<sub>OH</sub> curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOC<sup>TM</sup>) Circuitry Technology and Applications*, literature number SCEA009.

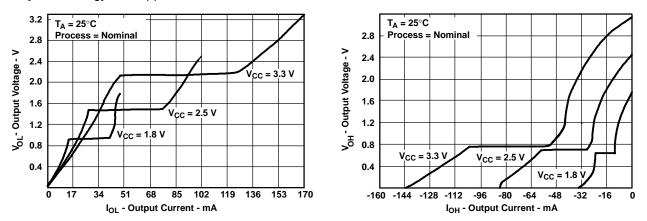
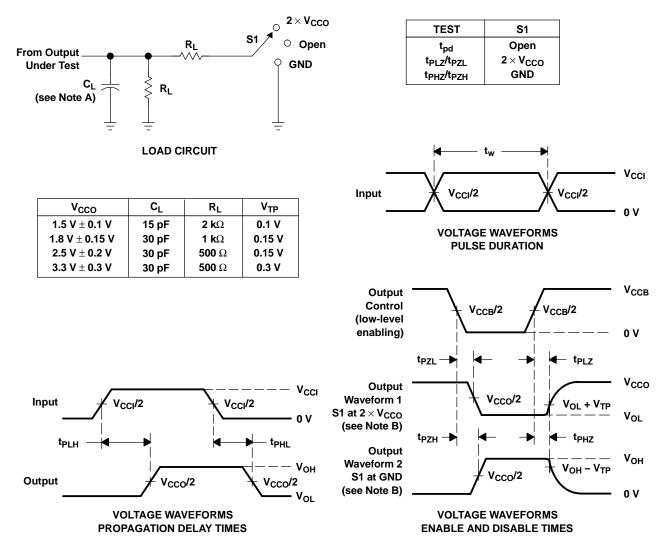


Figure 1. Typical Output Voltage vs Output Current





#### PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , dv/dt  $\geq$  1 V/ns, dv/dt  $\geq$ 1 V/ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - H.  $V_{CCI}$  is the  $V_{CC}$  associated with the input port.
  - I.  $V_{CCO}$  is the  $V_{CC}$  associated with the output port.

#### Figure 2. Load Circuit and Voltage Waveforms



27-Dec-2019

## PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
74AVCB324245ZKER	NRND	LFBGA	ZKE	96	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	-40 to 85	WD4245	
SN74AVCB324245KR	NRND	LFBGA	GKE	96	1000	TBD	SNPB	Level-2-235C-1 YEAR	-40 to 85	WD4245	

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption. **Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74AVCB324245ZKER	LFBGA	ZKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1
SN74AVCB324245KR	LFBGA	GKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1

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# PACKAGE MATERIALS INFORMATION

14-Oct-2017



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74AVCB324245ZKER	LFBGA	ZKE	96	1000	336.6	336.6	41.3
SN74AVCB324245KR	LFBGA	GKE	96	1000	336.6	336.6	41.3

GKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MO-205 variation CC.
  - D. This package is tin-lead (SnPb). Refer to the 96 ZKE package (drawing 4204493) for lead-free.



ZKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Falls within JEDEC MO-205 variation CC.

D. This package is lead-free. Refer to the 96 GKE package (drawing 4188953) for tin-lead (SnPb).



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